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DATE MAILED: 05/08/2003

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/761,693	01/18/2001	Masaru Tsukiji	DP-706 US	4695
466	7590 05:08:2003			
YOUNG & THOMPSON 745 SOUTH 23RD STREET 2ND FLOOR ARLINGTON, VA 22202			EXAMINER	
			ABRAHAM, FETSUM	
			ART UNIT	PAPER NUMBER
			2826	

Please find below and/or attached an Office communication concerning this application or proceeding.

		1	<del></del>			
•	•	Application No.	Applicant(s)			
		09/761,693	TSUKIJI, MASARU			
	Office Action Summary	Examiner	Art Unit			
		Fetsum Abraham	2826			
Perioû fo	- The MAILING DATE of this communication app	pears on the cover sheet wit	th the correspondence address			
A SHO THE N - Exten after S - If the - If NO	DRTENED STATUTORY PERIOD FOR REPLINALING DATE OF THIS COMMUNICATION. sions of time may be available under the provisions of 37 CFR 1.1 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a repliperiod for reply is specified above, the maximum statutory period of the reply within the set or extended period for reply will, by statute	36(a). In no event, however, may a re y within the statutory minimum of thirty will apply and will expire SIX (6) MON's. cause the application to become AB.	reply be timely filed  r (30) days will be considered timely  FHS from the mailing date of this communication  ANDONED (35 U.S.C. § 133).			
	eply received by the Office later than three months after the mailing dipatent term adjustment. See 37 CFR 1.704(b).	g date of this communication, even if the	mely filed, may reduce any			
Status	_					
1)[	Responsive to communication(s) filed on 25 i					
2a) 🗌	,	nis action is non-final.				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.  Disposition of Claims						
-		า				
4) Claim(s) 1-13 is/are pending in the application.						
4a) Of the above claim(s) is/are withdrawn from consideration.						
· —	Claim(s) is/are allowed.					
	Claim(s) <u>1-13</u> is/are rejected.					
,	Claim(s) is/are objected to.	a a la ation no accionno at				
• -	Claim(s) are subject to restriction and/o on Papers	or election requirement.				
· —	The specification is objected to by the Examine					
10) 🔲 🗀	The drawing(s) filed on is/are: a)□ acce					
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.						
If approved, corrected drawings are required in reply to this Office action.						
12)	The oath or declaration is objected to by the Ex	xaminer.				
	ınder 35 U.S.C. §§ 119 and 120					
13)⊡	Acknowledgment is made of a claim for foreig	n priority under 35 U.S.C.	§ 119(a)-(d) or (f).			
a)[	⊠ All b) ☐ Some * c) ☐ None of:					
	1. Certified copies of the priority documen					
	2. Certified copies of the priority documen	ts have been received in A	pplication No			
* 5	3. Copies of the certified copies of the price application from the International Bushes the attached detailed Office action for a list	ureau (PCT Rule 17.2(a)).				
14) A	Acknowledgment is made of a claim for domest	tic priority under 35 U.S.C.	§ 119(e) (to a provisional application).			
a 15)□ /	) The translation of the foreign language pr Acknowledgment is made of a claim for domes	ovisional application has b	een received.			
2) Notic	te of References Cited (PTO-892) te of Draftsperson's Patent Drawing Review (PTO-948) mation Discosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of	Summary (PTO-413) Paper No(s) Informal Patent Application (PTO-152)			

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## Claims rejection

the allowable claims in the last actions have been withdrawn in light of the newly discovered document.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

1. Claims 1-12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Tang et al (5.190.887)

The patent discloses a non-volatile memory structure in figure 12 having a cell with floating gate (62), the gate's region of overlap with drain (71) being larger than its region of overlap with the source (101 but omits to identify the structure as a NOR type memory device. However, logical circuits are inherent to the making of memory devices that it would have been obvious to one skilled in the art to expect such gates as parts of the overall circuit of the memory structure in the patent.

As for claim, "dimensions" are notoriously known to be variable in the art solely depending on device size, convenience of fabrication steps and time and are considered to be design choices unless proven critical. In this case, the specification contains no disclosure of either the critical nature of the claimed arrangement or any unexpected results arising therefrom. Where patentability is said to be based upon particular chosen dimensions or upon another variable recited in a claim, the applicant must show that the chosen dimensions are critical. In re Woodruff, 919 F.2d 1575, 1578, 16 USPQ2d 1934, 1936 (Fed. Cir. 1990).

As for claim 3, the patent discloses the advantages of graded sources in memory cells. In column 8, 44-60, it clearly underlines that graded source regions proximate to the substrate results in the possibility of using higher voltages to program the memory and also provides higher junction breakdown voltages.

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As for claims 4-9 figure 14 shows the claimed structure. The structure is provided will physically contacted or unified first and second source regions (126.127) and LDD (123) that partially overlap with the floating gate (62). As for claims 6.7, LDDs are always less doped than the active regions in all memory cells.

As for claim 10, an array of memory cells make up a complete memory device. Common source/drain structures are common in memory arrays and the claimed structure is shown in figures 13 and 14. As for the concentration of source being lowest than the drains, the patent as discussed above has graded sources that maximize junction breakdown voltages. Such structures have fewer average impurity concentrations that single doped drains.

As for claims 11,12, each memory structure is made to be isolated from adjacent ones.

This heavily minimizes cross talk effects and the method is standard to all memory cells in the art.

Beyond that, there is always one floating gate and one drain per cell in any memory array.

Any inquiry concerning this communication should be directed to Fetsum Abraham at telephone number (703) 305,3793, or by E-mail at *fetsum.abraham@uspto.gov*.

Any inquiry of a general nature or relating to the status of this application should be directed to the *SPE of AU*:2826 at (703)308-6601, or the *Group receptionist* at (703) 308-0956.

Fetsumabraham/4/31/03